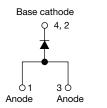
VS-15AWL06FN-M3, VS-15EWL06FN-M3

Vishay Semiconductors

Ultralow V_F Ultrafast Rectifier, 15 A FRED Pt®



DPAK (TO-252AA)





VS-15AWL06FN-M3

VS-15EWL06FN-M3

PRIMARY CHARACTERISTICS						
I _{F(AV)} 15 A						
V _R	600 V					
V _F at I _F	0.85 V					
t _{rr} (typ.)	60 ns					
T _J max.	175 °C					
Package	DPAK (TO-252AA)					
Circuit configuration	Single					

FEATURES

 \bullet Ultrafast recovery time, extremely low V_{F} and soft recovery



• 175 °C maximum operating junction temperature

For PFC DCM operation

COMPLIANT HALOGEN FREE

- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art, ultralow V_F , soft-switching hyperfast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V_{RRM}		600	V			
Average rectified forward current	I _{F(AV)}	T _C = 148 °C	15				
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	180	Α			
Peak repetitive forward current	I _{FM}	T _C = 148 °C, f = 20 kHz, d = 50 %	30				
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	.,	
Forward voltage	V	I _F = 15 A	-	0.99	1.05	V	
	V _F	I _F = 15 A, T _J = 150 °C	-	0.85	0.92		
Poverse leekage ourrent		$V_R = V_R$ rated	-	-	10		
Reverse leakage current	IR	$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	-	120	μA	
Junction capacitance	C _T	V _R = 600 V	-	11	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	=	nH	

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1 A, dI_F/dt = 10$	00 A/μs, V _R = 30 V	-	60	120			
Reverse recovery time	t _{rr}	$I_F = 15 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	190	-			
neverse recovery time		T _J = 25 °C	I _F = 15 A dI _F /dt = 200 A/μs V _R = 390 V	-	220	-	ns		
		T _J = 125 °C		=	290	-			
Poak rocoveny current	I _{RRM}	T _J = 25 °C		-	21	-	Α		
Peak recovery current		T _J = 125 °C		-	25	-	_ ^		
Daylaraa raaayar aharaa	Q _{rr}	T _J = 25 °C		-	2.6	-	- μC		
Reverse recovery charge		T _J = 125 °C		=	4	-			

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C	
Thermal resistance, junction to case	R _{thJC}		-	1.4	1.8	°C/W	
Thermal resistance, junction to ambient	R _{thJA}		-	-	70	C/VV	
Approximate weight			0.3		g		
Approximate weight				0.01		oz.	
Marking device	Coop at to DDAY (TO			15AWL06FN			
ivial killig device		Case style DPAK (TO-252AA)) 15E			VL06FN	

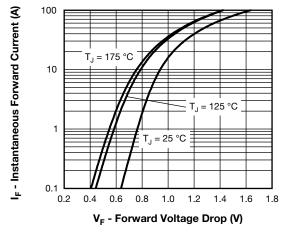


Fig. 1 - Typical Forward Voltage Drop Characteristics

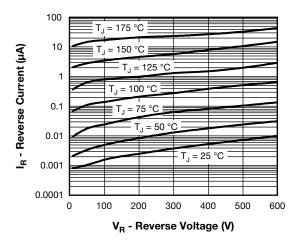


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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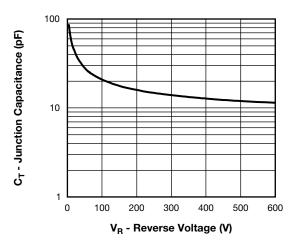


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

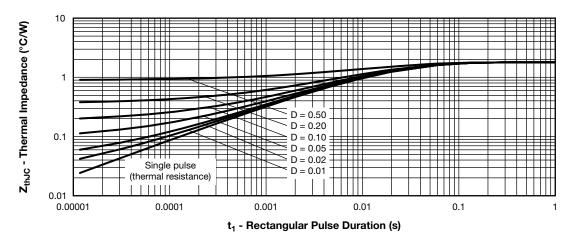


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

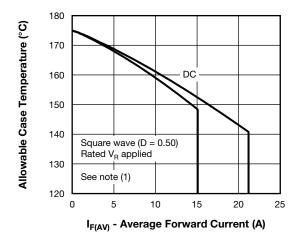


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

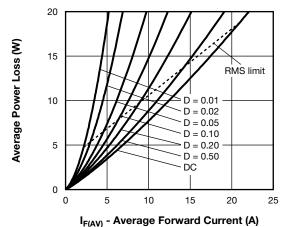
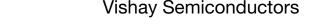


Fig. 6 - Forward Power Loss Characteristics

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = rated V_R$

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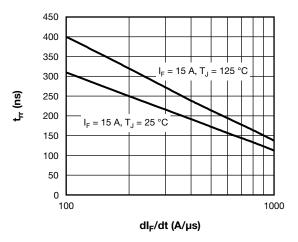


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

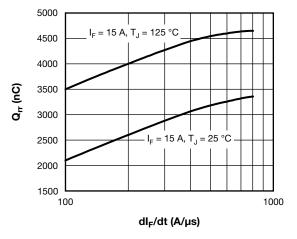
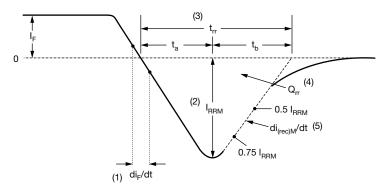


Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

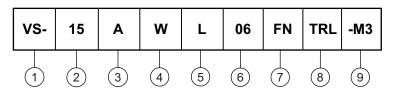
Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (15 = 15 A)

3 - Circuit configuration:

• A = single diode (2 anodes)

• E = single diode

4 - Package identifier:

W = DPAK

5 - L = hyperfast rectifier

6 - Voltage rating (06 = 600 V)

7 - FN = TO-252AA

8 - • None = tube

• TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

9 - Environmental digit:

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-15AWL06FN-M3	75	Antistatio plantia tuba					
VS-15EWL06FN-M3	75	Antistatic plastic tube					
VS-15AWL06FNTR-M3	2000	13" diameter reel					
VS-15EWL06FNTR-M3	2000	is diameter reel					
VS-15AWL06FNTRL-M3	3000	13" diameter reel					
VS-15EWL06FNTRL-M3	3000	is diameter reel					
VS-15AWL06FNTRR-M3	2000	10" diameter real					
VS-15EWL06FNTRR-M3	3000	13" diameter reel					

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95627				
Part marking information	www.vishay.com/doc?95176				
Packaging information	www.vishay.com/doc?95033				
SPICE model	www.vishay.com/doc?95372				



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D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	INCHES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	1	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
OTWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51	BSC	0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC® outline TO-252AA



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